

HD74HC352

# Dual 4-to-1-line Data Selectors/Multiplexers

REJ03D0611-0200 (Previous ADE-205-490) Rev.2.00 Jan 31, 2006

# Description

Each of these data selectors/multiplexers contains inverters and drivers to supply fully complementary binary decoding data selection to the AND-OR-invert gates. Separate strobe inputs (G) are provided for each of the two four-line sections.

# Features

- High Speed Operation:  $t_{pd}$  (Data to Y) = 16 ns typ ( $C_L = 50 \text{ pF}$ )
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max (Ta = 25°C)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC352RPEL	SOP-16 pin (JEDEC)	PRSP0016DG-A (FP-16DNV)	RP	EL (2,500 pcs/reel)

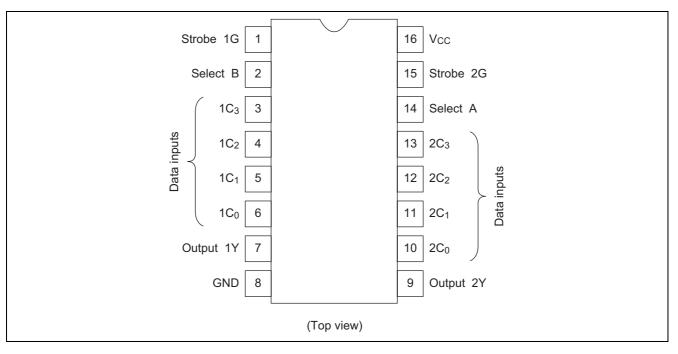
# **Function Table**

Selec	t Input		Data I	Strobe	Output		
В	Α	C <sub>0</sub>	<b>C</b> <sub>1</sub>	C <sub>2</sub>	<b>C</b> <sub>3</sub>	G	Y
Х	Х	Х	Х	Х	Х	Н	Н
L	L	L	Х	Х	Х	L	Н
L	L	Н	Х	Х	Х	L	L
L	Н	Х	L	Х	Х	L	Н
L	Н	Х	Н	Х	Х	L	L
Н	L	Х	Х	L	Х	L	Н
Н	L	Х	Х	Н	Х	L	L
Н	Н	Х	Х	Х	L	L	Н
Н	Н	Х	Х	Х	Н	L	L

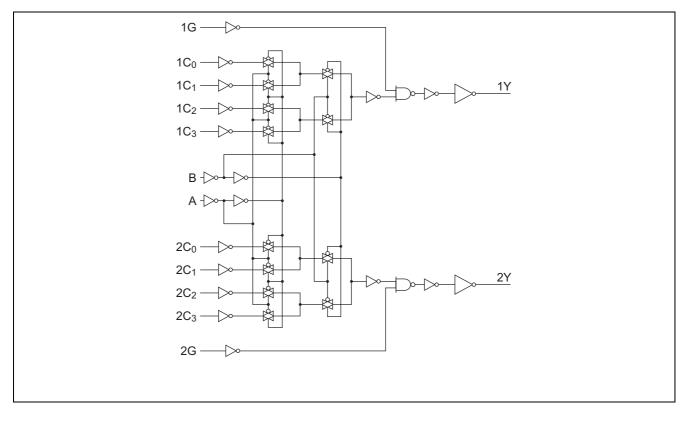
Select inputs A and B are common to both sections



# **Pin Arrangement**



# Logic Diagram



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# **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> +0.5	V
Input / Output diode current	I <sub>IK</sub> , I <sub>OK</sub>	±20	mA
Output current	lo	±25	mA
V <sub>CC</sub> , GND current	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA
Power dissipation	PT	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

# **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions	
Supply voltage	V <sub>CC</sub>	2 to 6	V		
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	0 to V <sub>CC</sub>	V		
Operating temperature	Та	-40 to 85	°C		
Input rise / fall time <sup>*1</sup>	t <sub>r</sub> , t <sub>f</sub>	0 to 1000	ns	V <sub>CC</sub> = 2.0 V	
		0 to 500		$V_{CC} = 4.5 V$	
		0 to 400		$V_{CC} = 6.0 V$	

Notes: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

ltom	Symbol		Т	a = 25°	С	Ta = -40	to+85°C	Unit	Test Car	ditiono
ltem	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions	
Input voltage	VIH	2.0	1.5	_		1.5	—	V		
		4.5	3.15	_		3.15	—			
		6.0	4.2	_		4.2	—			
	VIL	2.0	_	_	0.5	—	0.5	V		
		4.5	_	_	1.35	—	1.35			
		6.0	_	_	1.8	—	1.8			
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0		1.9	—	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \ \mu A$
		4.5	4.4	4.5		4.4	—	-		
		6.0	5.9	6.0		5.9	—			
		4.5	4.18	_		4.13	—			I <sub>ОН</sub> = -4 mA
		6.0	5.68			5.63	—			$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0		0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA
		4.5		0.0	0.1	_	0.1			
		6.0		0.0	0.1	_	0.1			
		4.5	_	_	0.26	—	0.33			$I_{OH} = 4 \text{ mA}$
		6.0			0.26	—	0.33			I <sub>OH</sub> = 5.2 mA
Input current	lin	6.0	_		±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GND	
Quiescent supply	Icc	6.0	_	_	4.0	_	40	μΑ	$Vin = V_{CC} \text{ or } GN$	ID, lout = $0 \mu A$
current										

## **Electrical Characteristics**

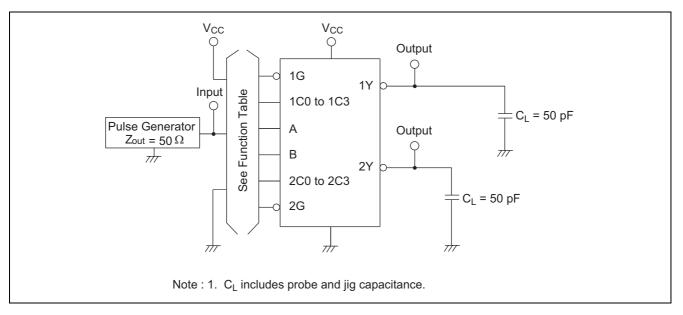


# **Switching Characteristics**

 $(C_L = 50 \text{ pF}, \text{ Input } t_r = t_f = 6 \text{ ns})$ 

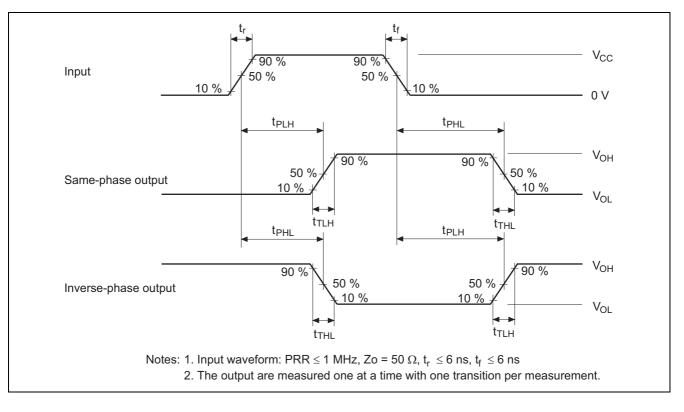
ltem	Symbol	V., 00	Т	a = 25°	С	Ta = -40	to +85°C	Unit	Test Conditions	
		V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max			
Propagation delay	t <sub>PLH</sub>	2.0	_	_	125	—	155	ns	Data to Y	
time	t <sub>PHL</sub>	4.5	_	16	25	_	31			
		6.0	_	_	21	_	26			
		2.0	_	_	160	_	200	ns	A or B to Y	
		4.5	_	18	32	_	40			
		6.0	_	_	27	_	34			
		2.0	_	_	100	_	125	ns	G to Y	
		4.5	_	10	20	_	25			
		6.0	_	_	17	_	21			
Output rise/fall	t <sub>TLH</sub>	2.0	_	_	75	—	95	ns		
time	$t_{THL}$	4.5	_	5	15	—	19			
		6.0		_	13	—	16			
Input capacitance	Cin	—	—	5	10	—	10	pF		

# **Test Circuit**



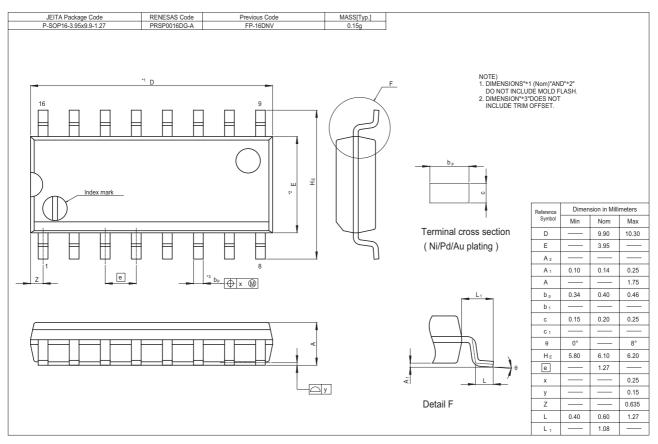


# Waveforms





# **Package Dimensions**





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